



PRODUCT DATA SHEET



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Datasheet

es Samples

Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO_questions@jgsemi.com.

2-Line Bi-directional ESD Diode

Features

- 420W peak pulse power (8/20µs)
- Protects two bi-directional lines
- Ultra low leakage: nA level
- Operating voltage: 24V
- Low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-4 (EFT) 40A (5/50ns)
- IEC61000-4-5 (Lightning) 9A (8/20μs)
- RoHS Compliant

Applications

- Cellular Handsets and Accessories
- Notebooks and Handhelds
- Portable Instrumentation
- Set Top Box
- Industrial Controls
- Server and Desktop PC
- CAN BUS PROTECTION

Mechanical Characteristics

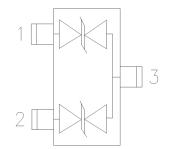
- Package: SOT-23
- Lead Finish: Lead Free
- UL Flammability Classification Rating 94V-0
- Quantity Per Reel:3,000pcs
- Reel Size:7inch

Absolute Maximum Ratings(Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20μs)	Ppk	420	W	
Peak Pulse Current (8/20μs)	IPP	9	A	
ESD per IEC 61000-4-2 (Air)	VECD	±30	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±30		
Operating Temperature Range	TJ	-55 to +125	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	



SOT-23



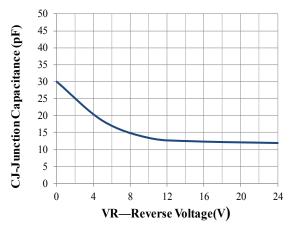


Electrical Characteristics (TA=25°C unless otherwise specified)

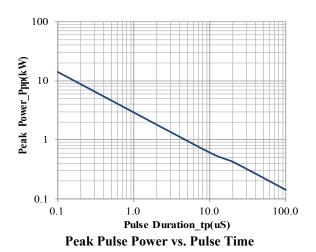
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	Vrwm				24	V
Breakdown Voltage	VBR	$I_T = 1 \text{mA}$	26	28.5	30. 5	V
Reverse Leakage Current	I_R	$V_{RWM} = 24V$			0.5	μΑ
Clamping Voltage	Vc	IPP = $1A (8 \times 20 \mu s \text{ pulse})$		35	40	V
Clamping Voltage	Vc	$I_{PP} = 9A (8 \times 20 \mu s \text{ pulse})$		45	58	V
Junction Capacitance	Сл	VR = 0V, f = 1MHz		30	50	pF



Characteristic Curves



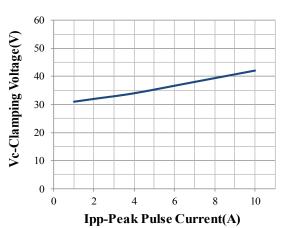
Junction Capacitance vs. Reverse Voltage



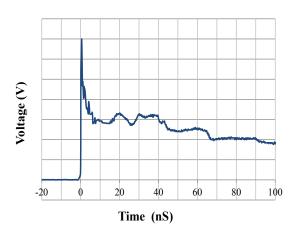
% of Rated Power 20 0 100 0 25 50 75 125 150

Power Derating Curve

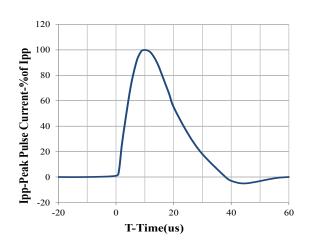
Ambient Temperature_Ta(℃)



Clamping Voltage vs. Peak Pulse Current



IEC61000-4-2 Pulse Waveform



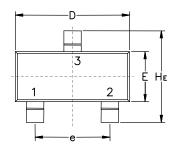
8 X 20us Pulse Waveform

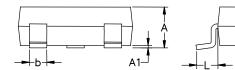
120

100



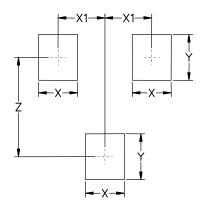
SOT-23 Package Outline & Dimensions





Symbol	М	illimete	rs		Inches	
	Min.	Nom.	Max.	Min.	Nom.	Max.
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.15	0.18	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

Soldering Footprint



Symbol	Millimeters	Inches
х	0.80	0.031
X1	0.95	0.037
Υ	0.90	0.035
Z	2.00	0.079



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